TEMIC
Semiconductors

DG189/190/191

High-Speed Drivers with Dual SPDT JFET Switches

Features

- Constant On-Resistance Over Entire Analog Range
- Low Leakage
- Low Crosstalk
- Rad Hardness

Benefits

- Low Distortion
- Eliminates Large Signal Errors
- High Precision
- High Bandwidth Capability
- Fault Protection

Applications

- Audio Switching
- Video Switching
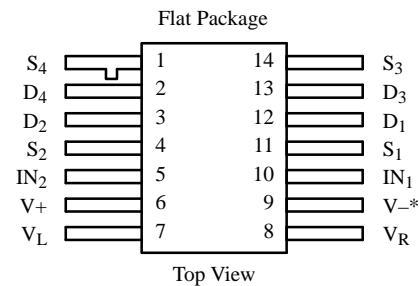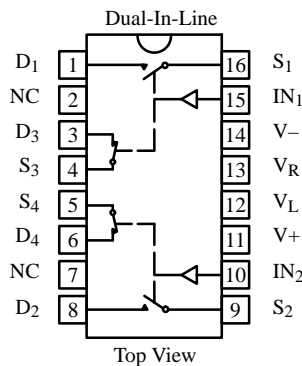- Sample/Hold
- Guidance and Control Systems
- Aerospace

Description

The DG189/190/191 are precision dual single-pole, double-throw (SPDT) analog switches designed to provide accurate switching of video and audio signals. This series is ideally suited for applications requiring a constant on-resistance over the entire analog range.

The major difference in the devices is the on-resistance (DG189—10 Ω, DG190—30 Ω, DG191—75 Ω). Reduced errors are achieved through low leakage current ($I_{D(on)}$ < 2 nA). Applications which benefit from the flat JFET on-resistance include audio switching, video switching, and data acquisition.

To achieve fast and accurate switch performance, each device comprises four n-channel JFET transistors and a TTL compatible bipolar driver. The driver is designed to achieve break-before-make switching action, eliminating the inadvertent shorting between channels and the crosstalk which would result. In the on state, each switch conducts current equally well in either direction. In the off condition, the switches will block up to 20 V peak-to-peak, with feedthrough of less than –60 dB at 10 MHz.

Functional Block Diagram and Pin Configuration

Dual-In-Line

D_1	1	16 S_1
NC	2	15 IN_1
D_3	3	14 $V-$
S_3	4	13 V_R
S_4	5	12 V_L
D_4	6	11 $V+$
NC	7	10 IN_2
D_2	8	9 S_2

Top View

Flat Package

S_4	1	14 S_3
D_4	2	13 D_3
D_2	3	12 D_1
S_2	4	11 S_1
IN_2	5	10 IN_1
$V+$	6	9 $V-*$
V_L	7	8 V_R

Top View

Refer to JAN38510 Information, Military Section

*Common to Substrate and Case

Truth Table

Logic	SW_1, SW_2	SW_3, SW_4
0	OFF	ON
1	ON	OFF

Logic "0" $\leq$ 0.8 V
Logic "1" $\geq$ 2.4 V

Updates to this data sheet may be obtained via facsimile by calling Siliconix FaxBack, 1-408-970-5600. Please request FaxBack document #70034.

DG189/190/191

Ordering Information

Temp Range	Package	Part Number
–25 to 85°C	16-Pin Sidebraze	DG189BP
		DG190BP
		DG191BP
–55 to 125°C	16-Pin Sidebraze	DG189AP/883, 5962-9068901MEA
		DG190AP/883, JM38510/11107BEA
		DG191AP/883, JM38510/11108BEA
	14-Pin Flat Pack	JM38510/11107BXA
		JM38510/11108BXA

Absolute Maximum Ratings

V+ to V– . . . . 36 V

V+ to V_D . . . . 33 V

V_S, V_D to V– . . . . –0.3 to 33 V

V_D to V_D . . . . ± 22 V

V_L to V– . . . . 36 V

V_L to V_{IN} . . . . 8 V

V_L to V_R . . . . 8 V

V_{IN} to V_R . . . . 8 V

V_R to V– . . . . 27 V

V_R to V_{IN} . . . . 2 V

Current (S or D) DG189 . . . . 200 mA

Current (S or D) DG190, DG191 . . . . 30 mA

Current (All Other Pins) . . . . 30 mA

Storage Temperature . . . . –65 to 150°C

Power Dissipation[a]

16-Pin Sidebraze[b] . . . . 900 mW

14-Pin Flat Pack[c] . . . . 900 mW

Notes:
a.   All leads welded or soldered to PC Board.
b.   Derate 12 mW/°C above 75°C
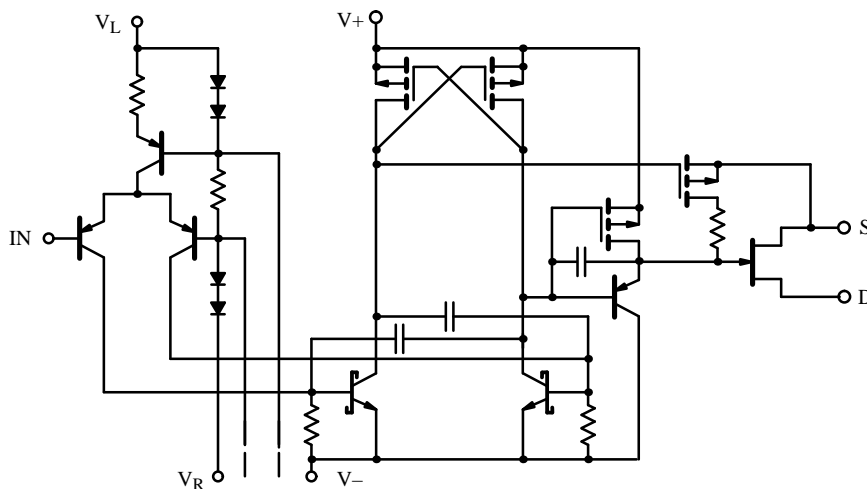c.   Derate 10 mW/°C above 75°C

Schematic Diagram (Typical Channel)

Figure 1.

Specifications[a] for DG189

Parameter	Symbol	Test Conditions Unless Otherwise Specified V+ = 15 V, V– = –15 V, V_L = 5 V V_R = 0 V, V_{IN} = 0.8 V or 2 V[f]	Temp[b]	Typ[c]	A Suffix –55 to 125°C Min[d]	Max[d]	B Suffix –25 to 85°C Min[d]	Max[d]	Unit
Analog Switch									
Analog Signal Range[e]	V_{ANALOG}		Full		–7.5	15	–7.5	15	V
Drain-Source On-Resistance	$r_{DS(on)}$	I_S = –10 mA, V_D = –7.5 V	Room Full	7.5		10 20		15 25	Ω
Source Off Leakage Current	$I_{S(off)}$	V_S = ± 10 V, V_D = ∓ 10 V V+ = 10 V, V– = –20 V	Room Hot	0.05		10 1000		15 300	nA
		V_S = ± 7.5 V, V_D = ∓ 7.5 V	Room Hot	0.05		10 1000		15 300	
Drain Off Leakage Current	$I_{D(off)}$	V_S = ± 10 V, V_D = ∓ 10 V V+ = 10 V, V– = –20 V	Room Hot	0.04		10 1000		15 300	
		V_S = ± 7.5 V, V_D = ∓ 7.5 V	Room Hot	0.03		10 1000		15 300	
Channel On Leakage Current	$I_{D(on)}$	V_D = V_S = ± 7.5 V	Room Hot	–0.1	–2 –200		–10 –200		
Saturation Drain Current	I_{DSS}	2 ms Pulse Duration	Room	300					mA
Digital Input									
Input Current with Input Voltage High	I_{INH}	V_{IN} = 5 V	Room Hot	<0.01		10 20		10 20	μA
Input Current with Input Voltage Low	I_{INL}	V_{IN} = 0 V	Full	–30	–250		–250		
Dynamic Characteristics									
Turn-On Time	t_{on}	See Switching Time Test Circuit	Room	240		400		425	ns
Turn-Off Time	t_{off}		Room	140		200		225	
Source-Off Capacitance	$C_{S(off)}$	f = 1 MHz / V_S = –5 V, I_D = 0	Room	21					pF
Drain-Off Capacitance	$C_{D(off)}$	V_D = –5 V, I_S = 0	Room	17					
Channel-On Capacitance	$C_{D(on)}$	V_D = V_S = 0 V	Room	17					
Off Isolation	OIRR	f = 1 MHz, R_L = 75 Ω	Room	>55					dB
Power Supplies									
Positive Supply Current	I+	V_{IN} = 0 V, or 5 V	Room	0.6		1.5		1.5	mA
Negative Supply Current	I–		Room	–2.7	–5		–5		
Logic Supply Current	I_L		Room	3.1		4.5		4.5	
Reference Supply Current	I_R		Room	–1	–2		–2		

Notes:
a. Refer to PROCESS OPTION FLOWCHART.
b. Room = 25°C, Full = as determined by the operating temperature suffix.
c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
e. Guaranteed by design, not subject to production test.
f. V_{IN} = input voltage to perform proper function.

Specifications[a] for DG190

Parameter	Symbol	Test Conditions Unless Otherwise Specified V+ = 15 V, V− = −15 V, V$_L$ = 5 V V$_R$ = 0 V, V$_{IN}$ = 0.8 V or 2 V[f]	Temp[b]	Typ[c]	A Suffix −55 to 125°C		B Suffix −25 to 85°C		Unit
					Min[d]	Max[d]	Min[d]	Max[d]	
Analog Switch									
Analog Signal Range[e]	V$_{ANALOG}$		Full		−7.5	15	−7.5	15	V
Drain-Source On-Resistance	r$_{DS(on)}$	I$_S$ = −10 mA, V$_D$ = −7.5 V	Room Full	18		30 60		50 75	Ω
Source Off Leakage Current	I$_{S(off)}$	V$_S$ = ± 10 V, V$_D$ = ∓ 10 V V+ = 10 V, V− = −20 V	Room Hot	0.06		1 100		5 100	nA
		V$_S$ = ± 7.5 V, V$_D$ = ∓ 7.5 V	Room Hot	0.1		1 100		5 100	
Drain Off Leakage Current	I$_{D(off)}$	V$_S$ = ± 10 V, V$_D$ = ∓ 10 V V+ = 10 V, V− = −20 V	Room Hot	0.05		1 100		5 100	
		V$_S$ = ± 7.5 V, V$_D$ = ∓ 7.5 V	Room Hot	0.06		1 100		5 100	
Channel On Leakage Current	I$_{D(on)}$	V$_D$ = V$_S$ = ± 7.5 V	Room Hot	−0.02	−2 −200		−10 −200		
Digital Input									
Input Current with Input Voltage High	I$_{INH}$	V$_{IN}$ = 5 V	Room Hot	<0.01		10 20		10 20	μA
Input Current with Input Voltage Low	I$_{INL}$	V$_{IN}$ = 0 V	Full	−30	−250		−250		
Dynamic Characteristics									
Turn-On Time	t$_{on}$	See Switching Time Test Circuit	Room	85		150		180	ns
Turn-Off Time	t$_{off}$		Room	95		130		150	
Source-Off Capacitance	C$_{S(off)}$	f = 1 MHz, V$_S$ = −5 V, I$_D$ = 0	Room	9					pF
Drain-Off Capacitance	C$_{D(off)}$	V$_D$ = −5 V, I$_S$ = 0	Room	6					
Channel-On Capacitance	C$_{D(on)}$	V$_D$ = V$_S$ = 0 V	Room	14					
Off Isolation	OIRR	f = 1 MHz, R$_L$ = 75 Ω	Room	>50					dB
Power Supplies									
Positive Supply Current	I+	V$_{IN}$ = 0 V, or 5 V	Room	0.6		1.5		1.5	mA
Negative Supply Current	I−		Room	−2.7	−5		−5		
Logic Supply Current	I$_L$		Room	3.1		4.5		4.5	
Reference Supply Current	I$_R$		Room	−1	−2		−2		

Notes:
a. Refer to PROCESS OPTION FLOWCHART.
b. Room = 25°C, Full = as determined by the operating temperature suffix.
c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
e. Guaranteed by design, not subject to production test.
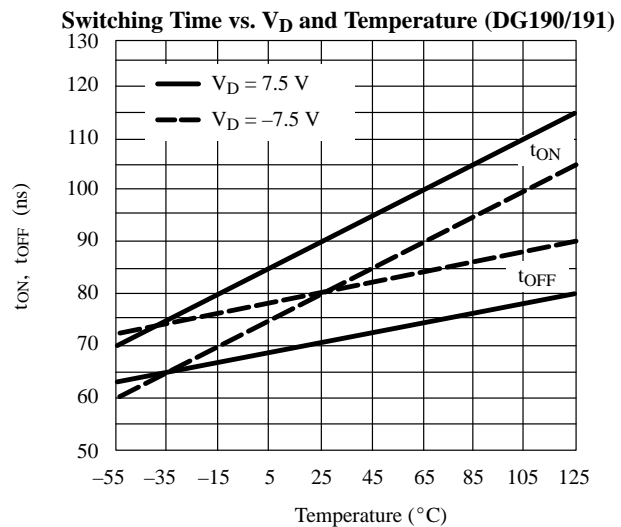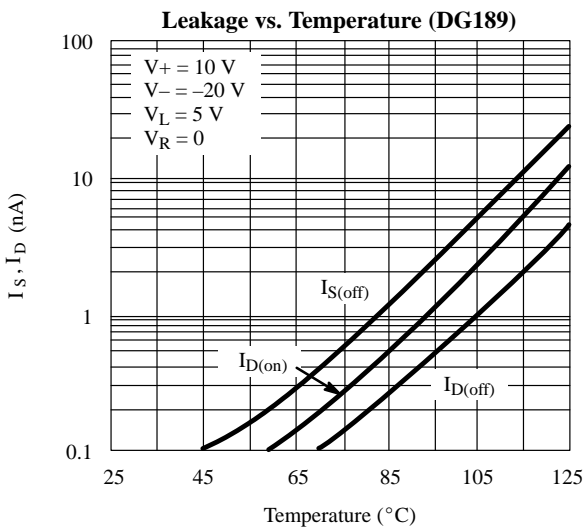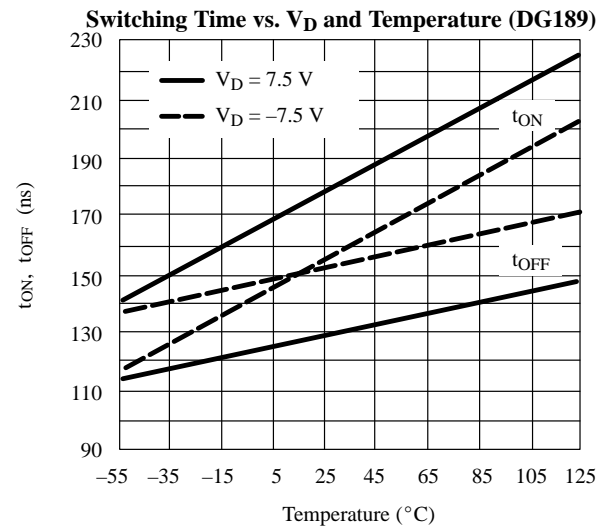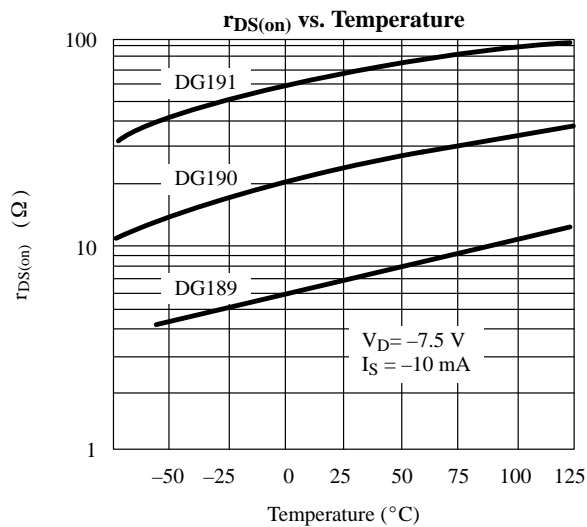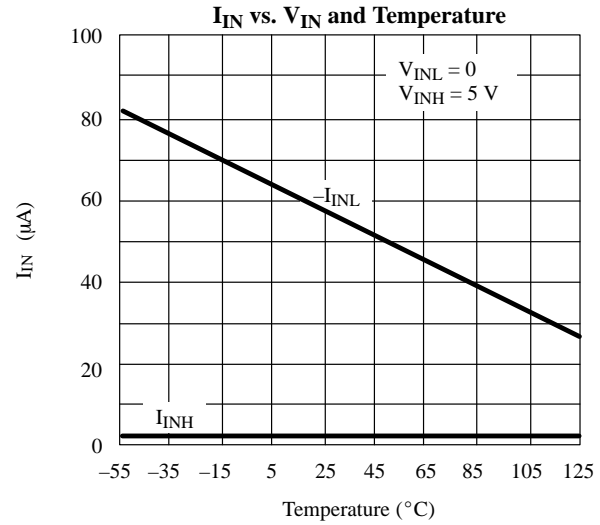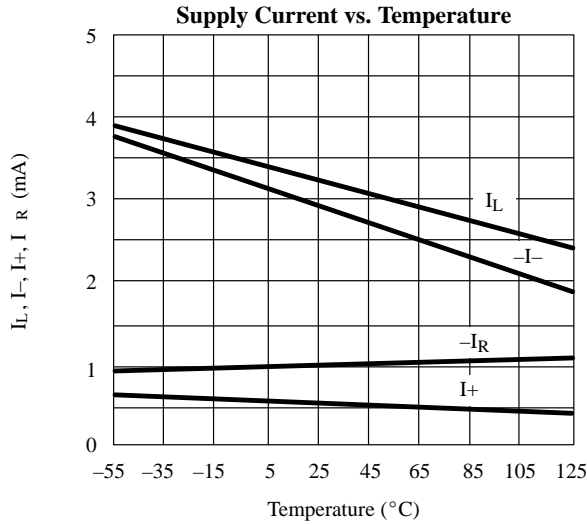f. V$_{IN}$ = input voltage to perform proper function.

Specifications[a] for DG191

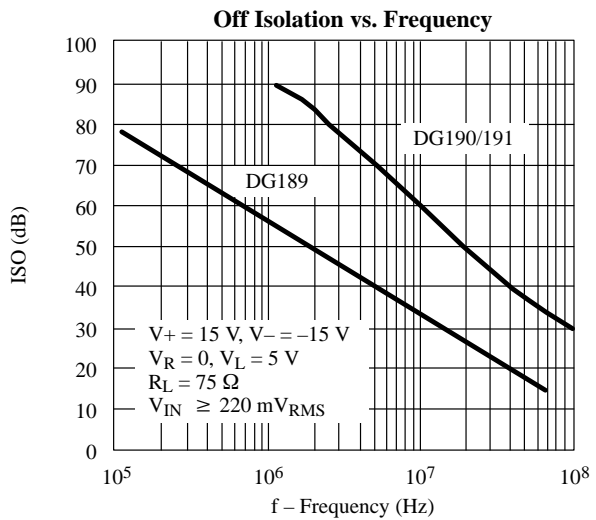| Parameter	Symbol	Test Conditions Unless Otherwise Specified $V+ = 15\,V, V- = -15\,V, V_L = 5\,V$ $V_R = 0\,V, V_{IN} = 0.8\,V$ or $2\,V^f$	Temp[b]	Typ[c]	A Suffix −55 to 125°C Min[d]	Max[d]	B Suffix −25 to 85°C Min[d]	Max[d]	Unit
Analog Switch									
Analog Signal Range[e]	V_{ANALOG}		Full		−10	15	−10	15	V
Drain-Source On-Resistance	$r_{DS(on)}$	$I_S = -10\,mA, V_D = -7.5\,V$	Room Full	35		75 150		100 150	Ω
Source Off Leakage Current	$I_{S(off)}$	$V_S = \pm 10\,V, V_D = \mp 10\,V$ $V+ = 10\,V, V- = -20\,V$	Room Hot	0.05		1 100		5 100	nA
		$V_S = \pm 10\,V, V_D = \mp 10\,V$	Room Hot	0.07		1 100		5 100	
Drain Off Leakage Current	$I_{D(off)}$	$V_S = \pm 10\,V, V_D = \mp 10\,V$ $V+ = 10\,V, V- = -20\,V$	Room Hot	0.04		1 100		5 100	
		$V_S = \pm 10\,V, V_D = \mp 10\,V$	Room Hot	0.05		1 100		5 100	
Channel On Leakage Current	$I_{D(on)}$	$V_D = V_S = \pm 10\,V$	Room Hot	−0.03	−2 −200		−10 −200		
Digital Input									
Input Current with Input Voltage High	I_{INH}	$V_{IN} = 5\,V$	Room Hot	<0.01		10 20		10 20	µA
Input Current with Input Voltage Low	I_{INL}	$V_{IN} = 0\,V$	Full	−30	−250		−250		
Dynamic Characteristics									
Turn-On Time	t_{on}	See Switching Time Test Circuit	Room	120		250		300	ns
Turn-Off Time	t_{off}		Room	100		130		150	
Source-Off Capacitance	$C_{S(off)}$	$f = 1\,MHz$ / $V_S = -5\,V, I_D = 0$	Room	9					pF
Drain-Off Capacitance	$C_{D(off)}$	$V_D = -5\,V, I_S = 0$	Room	6					
Channel-On Capacitance	$C_{D(on)}$	$V_D = V_S = 0\,V$	Room	14					
Off Isolation	OIRR	$f = 1\,MHz, R_L = 75\,\Omega$	Room	>50					dB
Positive Supply Current	I+	$V_{IN} = 0\,V$, or $5\,V$	Room	0.6		1.5		1.5	mA
Negative Supply Current	I−		Room	−2.7	−5		−5		
Logic Supply Current	I_L		Room	3.1		4.5		4.5	
Reference Supply Current	I_R		Room	−1	−2		−2		

Notes:
a. Refer to PROCESS OPTION FLOWCHART.
b. Room = 25°C, Full = as determined by the operating temperature suffix.
c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
e. Guaranteed by design, not subject to production test.
f. V_{IN} = input voltage to perform proper function.

Typical Characteristics

Supply Current vs. Temperature

I_{IN} vs. V_{IN} and Temperature

$r_{DS(on)}$ vs. Temperature

Switching Time vs. V_D and Temperature (DG189)

Leakage vs. Temperature (DG189)

Switching Time vs. V_D and Temperature (DG190/191)

Typical Characteristics (Cont'd)

$I_{D(off)}$ vs. Temperature (DG190/191)

V+ = 10 V, V– = –20 V
V_D = –10 V, V_S = 10 V

I_D (nA)

B Suffix

A Suffix

Temperature (°C)

Capacitance vs. V_D or V_S (DG189)

f = 1 MHz

$C_{S(off)}$

$C_{D(on)}$

$C_{D(off)}$

$C_{S, D}$ (pF)

V_D or V_S – Drain or Source Voltage (V)

Capacitance vs. V_D or V_S (DG190/191)

V_{INL} = 0.8 V
V_{INH} = 2 V
f = 1 MHz

$C_{D(on)}$

$C_{S(off)}$

$C_{D(off)}$

Capacitance is measured from test terminal to common.

$C_{S, D}$ (pF)

V_D or V_S – Drain or Source Voltage (V)

Off Isolation vs. Frequency

DG190/191

DG189

V+ = 15 V, V– = –15 V
V_R = 0, V_L = 5 V
R_L = 75 Ω
V_{IN} ≥ 220 mV_{RMS}

ISO (dB)

f – Frequency (Hz)

Test Circuits

Feedthrough due to charge injection may result in spikes at the leading and trailing edge of the output waveform.

+5 V +15 V
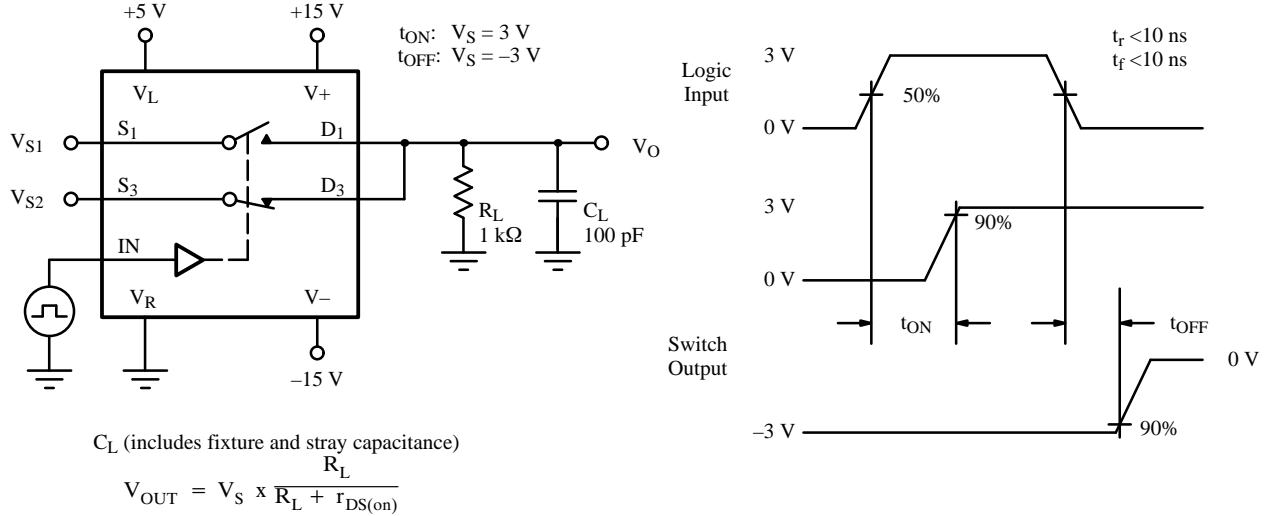
t_{ON}: V_S = 3 V
t_{OFF}: V_S = –3 V

V_L V+

V_{S1} ○ S_1 D_1

V_{S2} ○ S_3 D_3

IN

V_R V–

–15 V

R_L 1 kΩ C_L 100 pF V_O

C_L (includes fixture and stray capacitance)

$$V_{OUT} = V_S \times \frac{R_L}{R_L + r_{DS(on)}}$$

Logic Input: 3 V, 0 V, 50%, t_r <10 ns, t_f <10 ns

Switch Output: 3 V, 0 V, 90%, t_{ON}, –3 V, 90%, t_{OFF}, 0 V

Figure 2. Switching Time

Application Hints[a]

Switch	V+ Positive Supply Voltage (V)	V– Negative Supply Voltage (V)	V_L Logic Supply Voltage (V)	V_R Reference Supply Voltage (V)	V_{IN} Logic Input Voltage $V_{INH(min)}$/$V_{INL(max)}$ (V)	V_S Analog Voltage Range (V)
DG189 DG190	15[b]	–15	5	GND	2.0/0.8	–7.5 to 15
	10	–20	5	GND	2.0/0.8	–12.5 to 10
	12	–12	5	GND	2.0/0.8	–4.5 to 12
DG191	15[b]	–15	5	GND	2.0/0.8	–10 to 15
	10	–20	5	GND	2.0/0.8	–15 to 10
	12	–12	5	GND	2.0/0.8	–7 to 12

Notes:
a. Application Hints are for DESIGN AID ONLY, not guaranteed and not subject to production testing.
b. Electrical Parameter Chart based on V+ = 15 V, V_L = 5 V, V_R = GND